

DATA SHEET

74LVC377

Octal D-type flip-flop with data enable;
positive-edge trigger

Product specification
Supersedes data of 1996 Jun 06
IC24 Data Handbook

1998 Jul 29

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FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Conforms to JEDEC standard 8-1A
- Inputs accept voltages up to 5.5V
- CMOS low power consumption
- Direct interface with TTL levels
- Output drive capability 50Ω transmission lines @ 85°C

DESCRIPTION

The 74LVC377 is a low-voltage Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74LVC377 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. A common clock (CP) input loads all flip-flops simultaneously when the data enable $\bar{E}$ is LOW. The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding output (Qn) of the flip-flop. The $\bar{E}$ input must be stable only one set-up time prior to the LOW-to-HIGH transition for predictable operation.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay CP to Qn;	$C_L = 50\text{pF}$ $V_{CC} = 3.3\text{V}$	6.0	ns
f_{max}	Maximum clock frequency		230	MHz
C_I	Input capacitance		5.0	pF
C_{PD}	Power dissipation capacitance per flip-flop	$V_I = \text{GND to } V_{CC}^1$	22	pF

NOTES:

1 C_{PD} is used to determine the dynamic power dissipation (P_D in μW)

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; C_L = output load capacity in pF;

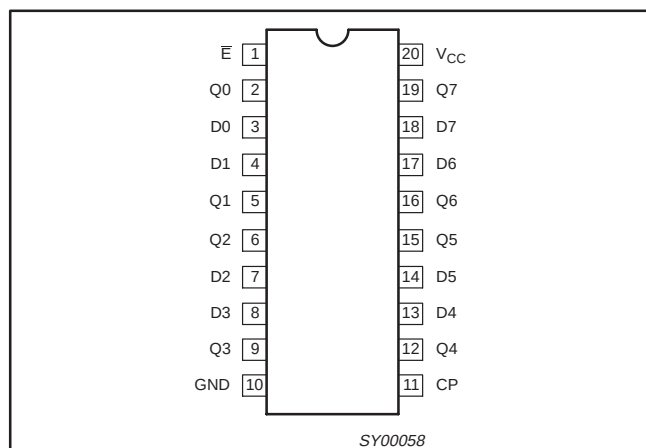
f_o = output frequency in MHz; V_{CC} = supply voltage in V;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SO	-40°C to $+85^{\circ}\text{C}$	74LVC377 D	74LVC377 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to $+85^{\circ}\text{C}$	74LVC377 DB	74LVC377 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to $+85^{\circ}\text{C}$	74LVC377 PW	74LVC377PW DH	SOT360-1

PIN CONFIGURATION



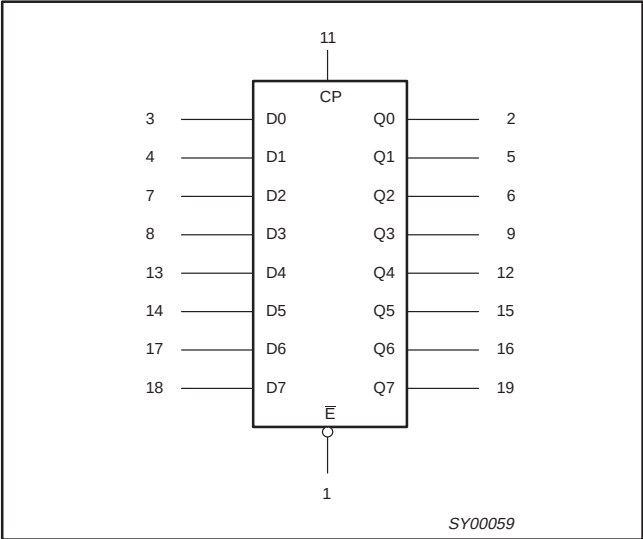
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	$\bar{E}$	Data enable input (active LOW)
2, 5, 6, 9, 12, 15, 16, 19	Q0 – Q7	Flip-flop outputs
3, 4, 7, 8, 13, 14, 17, 18	D0 – D7	Data inputs
10	GND	Ground (0V)
11	CP	Clock input (LOW-to-HIGH, edge-triggered)
20	V_{CC}	Positive power supply

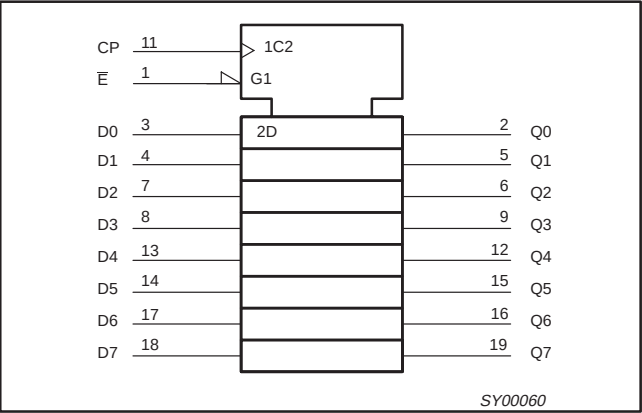
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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

OPERATING MODES	INPUTS			OUTPUT
	CP	$\overline{E}$	Dn	Qn
Load '1'	↑	l	h	H
Load '0'	↑	l	l	L
hold (do nothing)	↑ X	h H	X X	no change no change

H = HIGH voltage level
h = HIGH voltage level one set-up time
prior to the LOW-to-HIGH CP transition
L = LOW voltage level
l = LOW voltage level one set-up time
prior to the LOW-to-HIGH CP transition
↑ = LOW-to-HIGH transition
X = Don't care

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
V _I	DC Input voltage range		0	5.5	V
V _{I/O}	DC Input voltage range for I/Os		0	V _{CC}	V
V _O	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		−40	+85	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.2 to 2.7V V _{CC} = 2.7 to 3.6V	0 0	20 10	ns/V

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ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +6.5	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage	Note 2	-0.5 to +5.5	V
$V_{I/O}$	DC input voltage range for I/Os		-0.5 to $V_{CC} + 0.5$	V
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	± 50	mA
V_{OUT}	DC output voltage	Note 2	-0.5 to $V_{CC} + 0.5$	V
I_{OUT}	DC output source or sink current	$V_O = 0$ to V_{CC}	± 50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		± 100	mA
T_{stg}	Storage temperature range		-60 to +150	°C
P_{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2V	V _{CC}			V	
		V _{CC} = 2.7 to 3.6V	2.0				
V _{IL}	LOW level Input voltage	V _{CC} = 1.2V			GND	V	
		V _{CC} = 2.7 to 3.6V			0.8		
V _{OH}	HIGH level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.5			V	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -100μA	V _{CC} - 0.2	V _{CC}			
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.6				
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -24mA	V _{CC} - 1.0				
V _{OL}	LOW level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 12mA			0.40	V	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 100μA			0.20		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 24mA			0.55		
I _I	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V or GND	Not for I/O pins		± 0.1	± 5	μA
I _{IHZ} /I _{ILZ}	Input current for common I/O pins	V _{CC} = 3.6V; V _I = V _{CC} or GND			± 0.1	± 15	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 3.6V; V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND			0.1	± 10	μA
I _{CC}	Quiescent supply current	V _{CC} = 3.6V; V _I = V _{CC} or GND; I _O = 0			0.1	10	μA
ΔI _{CC}	Additional quiescent supply current	V _{CC} = 2.7V to 3.6V; V _I = V _{CC} - 0.6V; I _O = 0			5	500	μA

NOTES:

- All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.

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AC CHARACTERISTICS

GND = 0V; $t_r = t_f = 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$; $T_{\text{amb}} = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS						UNIT
			V _{CC} = 3.3V ±0.3V			V _{CC} = 2.7V			
			MIN	TYP ¹	MAX	MIN	TYP	MAX	
t _{PHL} t _{PLH}	Propagation delay CP to Qn	1		6.0	10.2		6.6	11.2	ns
t _W	Clock pulse width HIGH or LOW	1	4	1.0		5	1.6		ns
t _{su}	Set-up time E̅ to CP	2	4	2.3		5	2.9		ns
t _h	Hold time E̅ to CP	2	0	−2.2		0	−2.8		ns
t _{su}	Set-up time D _n to CP	3	2	1.3		3	1.8		ns
t _h	Hold time D _n to CP	3	0	−1.2		0	−1.6		ns
f _{max}	Maximum clock pulse frequency	1	125			100			MHz

NOTE:

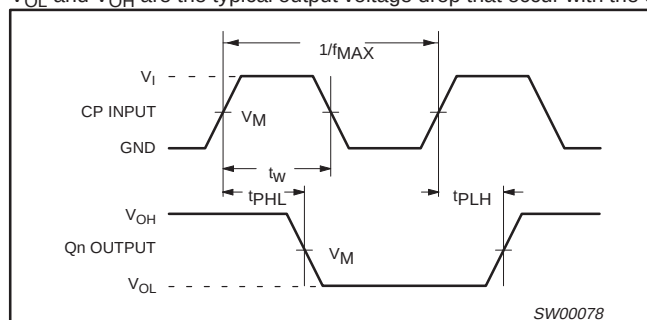
1. Unless otherwise stated, all typical values are at $V_{CC} = 3.3V$ and $T_{\text{amb}} = 25^\circ\text{C}$.

AC WAVEFORMS

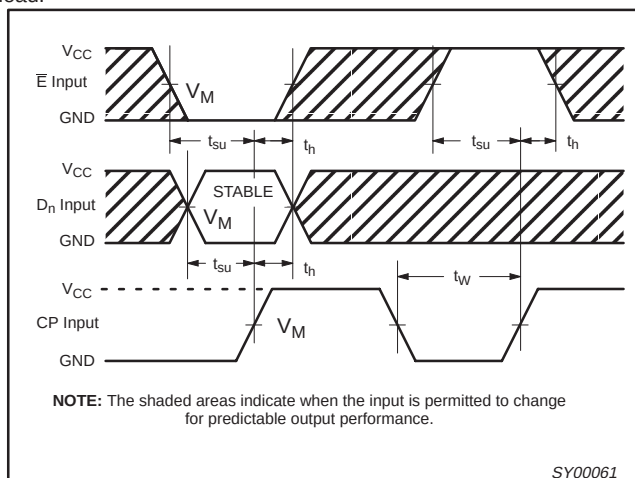
$V_M = 1.5V$ at $V_{CC} \geq 2.7V$.

$V_M = 0.5 V_{CC}$ at $V_{CC} < 2.7V$.

V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.



Waveform 1. Clock (CP) to output (Qn) propagation delays the clock pulse width and the maximum clock pulse frequency.

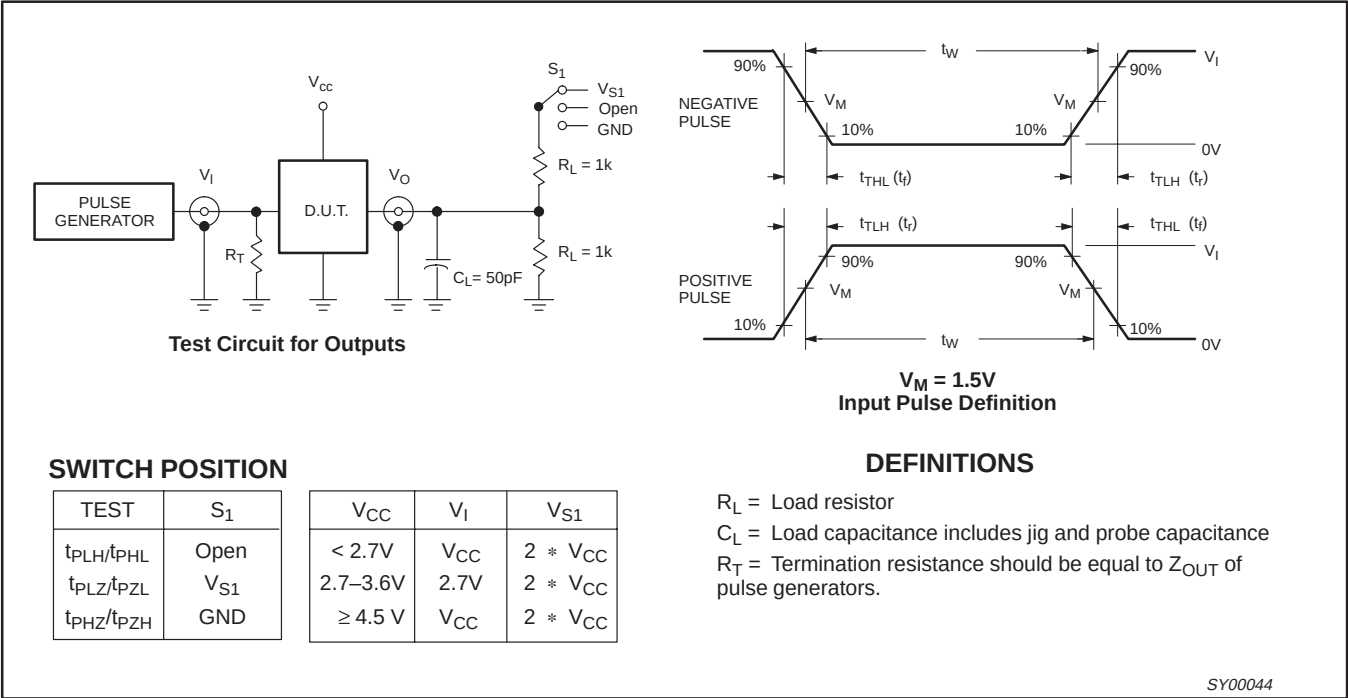


Waveform 2. Data set-up and hold times from the data input (D_n) and from the enable input ($\bar{E}$) to the clock (CP).

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TEST CIRCUIT



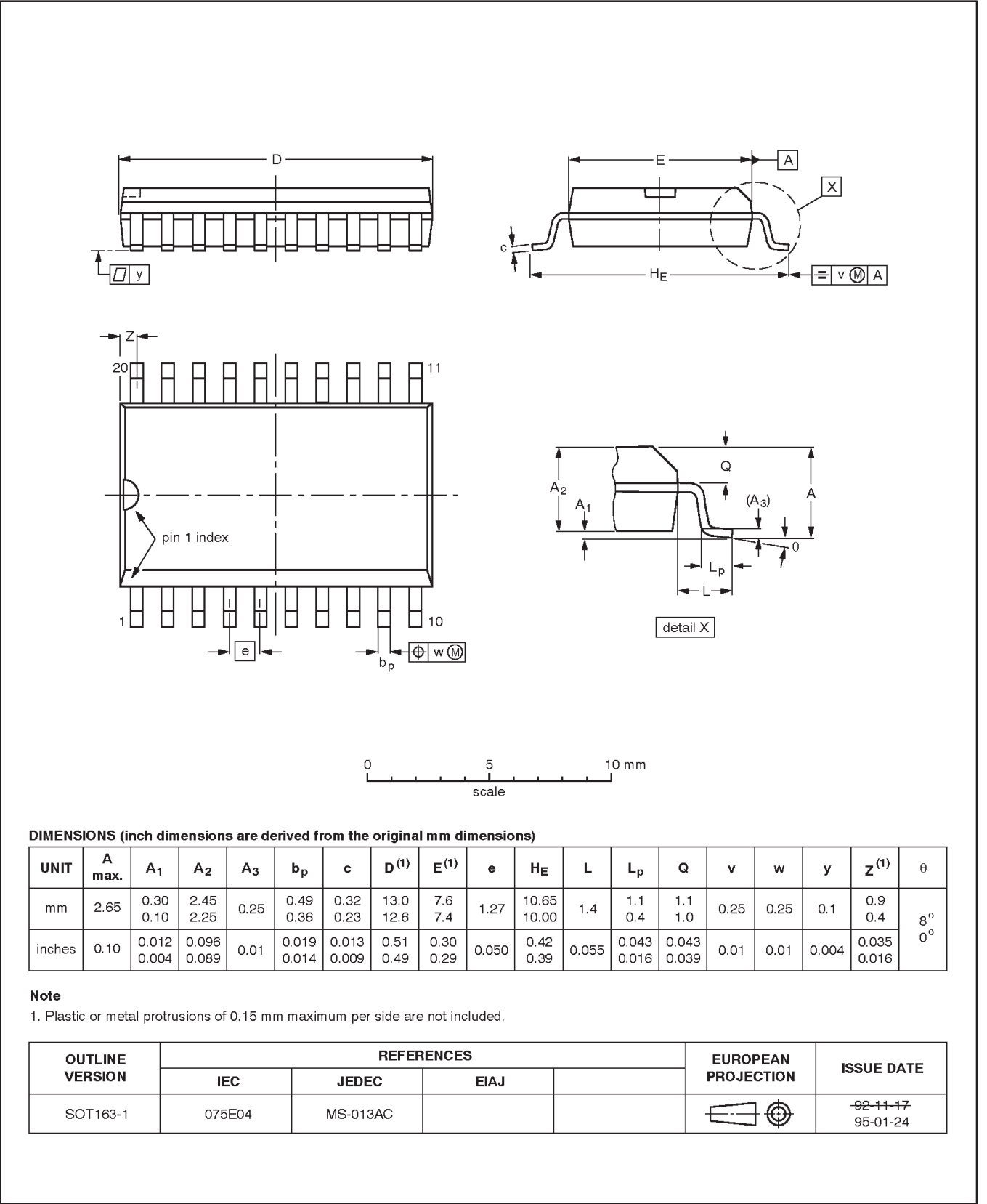
Waveform 3. Load circuitry for switching times.

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

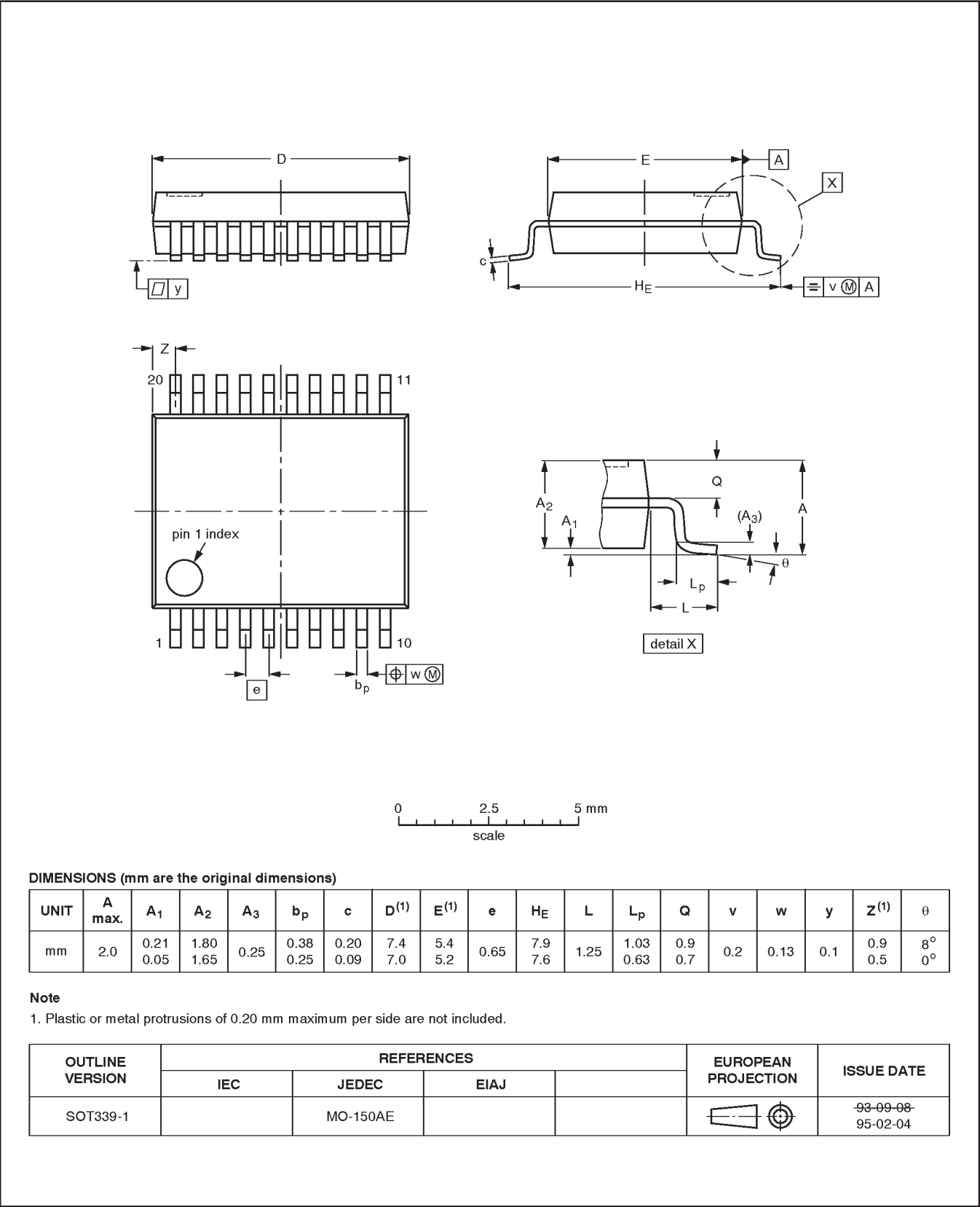


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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

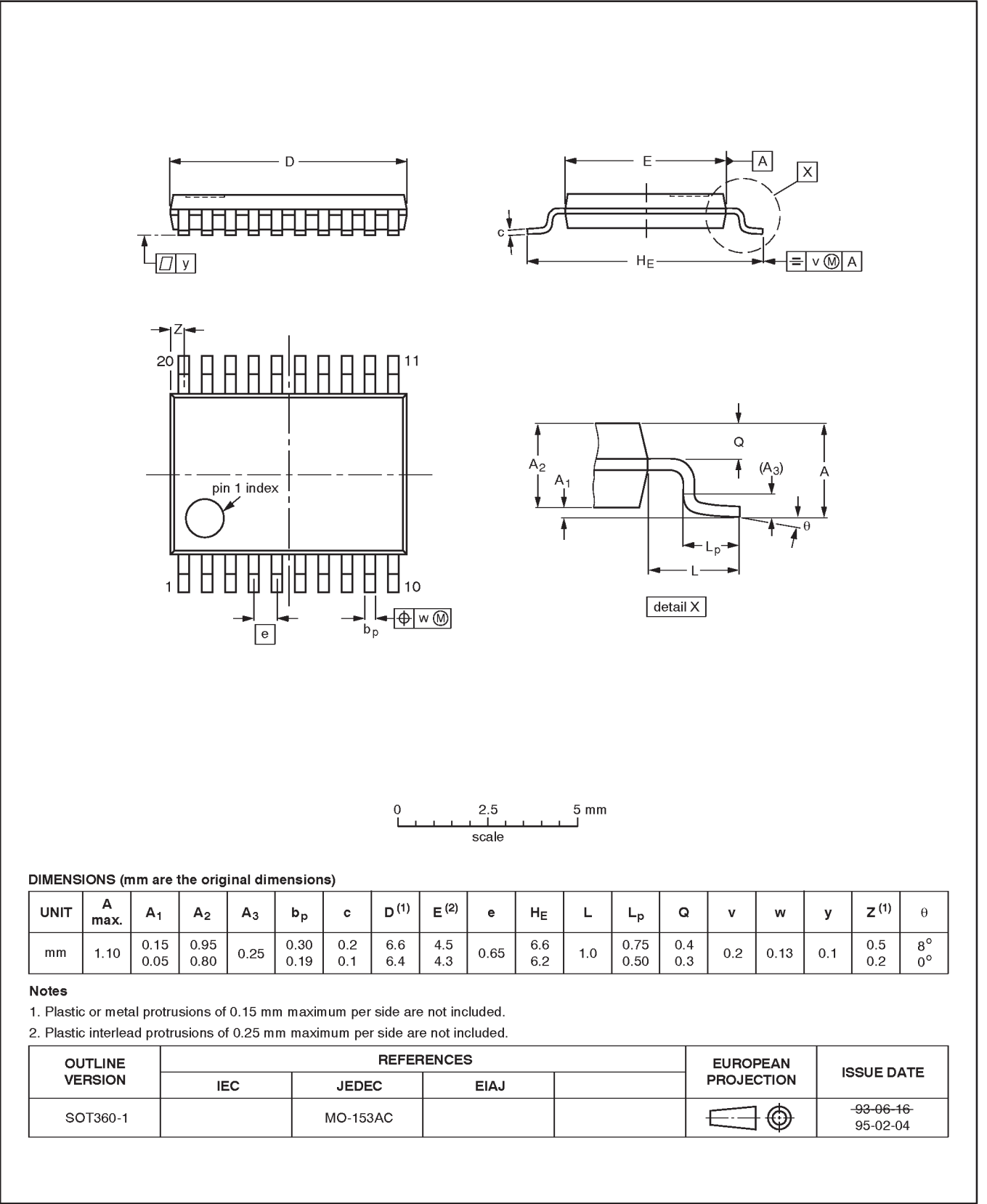


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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



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DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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